

# PSMN1R5-50YLH

N-channel 50 V, 1.7 mOhm, 200 A continuous, logic level MOSFET in LFPAK56E using NextPower-S3 technology 9 July 2021

**Product data sheet** 

### 1. General description

200 Amp continuous current, logic level gate drive, N-channel enhancement mode MOSFET in LFPAK56E package. Part of the ASFETs for Battery Isolation and DC Motor control family and using Nexperia's unique "SchottkyPlus" technology delivers high efficiency and low spiking performance usually associated with MOSFETs with an integrated Schottky or Schottky-like diode but without problematic high leakage current. The ASFET is particularly suited to 36 V battery powered applications requiring strong avalanche capability, linear mode performance, use at high switching frequencies, and also safe and reliable switching at high load-current.

### 2. Features and benefits

- 200 A continuous current capability
- Optimised for 36 V (nominal) battery powered applications
- LFPAK56E low-stress exposed lead-frame for ultimate reliability, optimum soldering and easy solder-joint inspection
- Copper-clip and solder die attach for low package inductance and resistance, and high I<sub>D (max)</sub> rating
- Qualified to 175 °C
- Avalanche rated, 100% tested
- Low Q<sub>G</sub>, Q<sub>GD</sub> and Q<sub>OSS</sub> for high efficiency, especially at higher switching frequencies
- Superfast switching with soft body-diode recovery for low-spiking and ringing, recommended for low EMI designs
- Unique "SchottkyPlus" technology for Schottky-like switching performance and low I<sub>DSS</sub> leakage
- Narrow V<sub>GS(th)</sub> rating for easy paralleling and improved current sharing
- Very strong linear-mode / safe operating area characteristics for safe and reliable switching at high-current conditions

# 3. Applications

- Brushless DC motor control
- Synchronous rectifier in high-power AC-to-DC applications, e.g. server power supplies
- Battery protection and Battery Management Systems (BMS)
- Load switch
- 10 cell lithium-ion battery applications (36 V 42 V)

### 4. Quick reference data

#### Table 1. Quick reference data

| Symbol           | Parameter               | Conditions                                                     |     | Min | Тур | Max | Unit |
|------------------|-------------------------|----------------------------------------------------------------|-----|-----|-----|-----|------|
| V <sub>DS</sub>  | drain-source voltage    | 25 °C ≤ T <sub>j</sub> ≤ 175 °C                                |     | -   | -   | 50  | V    |
| I <sub>D</sub>   | drain current           | V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u> | [1] | -   | -   | 200 | Α    |
| P <sub>tot</sub> | total power dissipation | T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>                         |     | -   | -   | 333 | W    |
| Tj               | junction temperature    |                                                                |     | -55 | -   | 175 | °C   |



technology

|                     |                                  |                                                                         |     |     |      | mology |
|---------------------|----------------------------------|-------------------------------------------------------------------------|-----|-----|------|--------|
| Symbol              | Parameter                        | Conditions                                                              | Min | Тур | Max  | Unit   |
| Static chara        | acteristics                      |                                                                         |     | •   |      | ·      |
| R <sub>DSon</sub>   | drain-source on-state resistance | $V_{GS}$ = 10 V; $I_{D}$ = 25 A; $T_{j}$ = 25 °C;<br>Fig. 10            | -   | 1.4 | 1.75 | mΩ     |
|                     |                                  | $V_{GS}$ = 4.5 V; $I_{D}$ = 25 A; $T_{j}$ = 25 °C;<br>Fig. 10           | -   | 1.6 | 2    | mΩ     |
| Dynamic ch          | naracteristics                   |                                                                         | •   |     |      |        |
| $Q_{GD}$            | gate-drain charge                | I <sub>D</sub> = 25 A; V <sub>DS</sub> = 25 V; V <sub>GS</sub> = 4.5 V; | -   | 13  | 29   | nC     |
| Q <sub>G(tot)</sub> | total gate charge                | Fig. 12; Fig. 13                                                        | -   | 53  | 82   | nC     |

<sup>[1] 200</sup>A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

## 5. Pinning information

### **Table 2. Pinning information**

| Pin | Symbol | Description                       | Simplified outline                      | Graphic symbol |
|-----|--------|-----------------------------------|-----------------------------------------|----------------|
| 1   | S      | source                            | (COO)                                   |                |
| 2   | S      | source                            |                                         |                |
| 3   | S      | source                            |                                         | D              |
| 4   | G      | gate                              |                                         |                |
| mb  | D      | mounting base; connected to drain | 1 2 3 4  LFPAK56E; Power- SO8 (SOT1023) | mbb076 S       |

## 6. Ordering information

Table 3. Ordering information

| Type number   | -    |                                                                                    |         |  |  |  |
|---------------|------|------------------------------------------------------------------------------------|---------|--|--|--|
|               | Name | Description                                                                        | Version |  |  |  |
| PSMN1R5-50YLH |      | plastic, single-ended surface-mounted package<br>(LFPAK56); 4 leads; 1.27 mm pitch | SOT1023 |  |  |  |

## 7. Marking

#### Table 4. Marking codes

| Type number   | Marking code |
|---------------|--------------|
| PSMN1R5-50YLH | 1H550L       |

# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol    | Parameter            | Conditions                               | Min | Max | Unit |
|-----------|----------------------|------------------------------------------|-----|-----|------|
| $V_{DS}$  | drain-source voltage | 25 °C ≤ T <sub>j</sub> ≤ 175 °C          | -   | 50  | V    |
| $V_{DGR}$ | drain-gate voltage   | 25 °C ≤ $T_j$ ≤ 175 °C; $R_{GS}$ = 20 kΩ | -   | 50  | V    |

| Symbol               | Parameter                                        | Conditions                                                                                                           |     | Min      | Max  | Unit |
|----------------------|--------------------------------------------------|----------------------------------------------------------------------------------------------------------------------|-----|----------|------|------|
| V <sub>GS</sub>      | gate-source voltage                              |                                                                                                                      |     | -20      | 20   | V    |
| P <sub>tot</sub>     | total power dissipation                          | T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>                                                                               |     | -        | 333  | W    |
| I <sub>D</sub>       | drain current                                    | V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>                                                       | [1] | -        | 200  | Α    |
|                      |                                                  | V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>                                                      |     | -        | 200  | Α    |
| I <sub>DM</sub>      | peak drain current                               | pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 °C$ ; Fig. 3                                                               |     | -        | 1159 | А    |
| T <sub>stg</sub>     | storage temperature                              |                                                                                                                      |     | -55      | 175  | °C   |
| Tj                   | junction temperature                             |                                                                                                                      |     | -55      | 175  | °C   |
| $T_{sld(M)}$         | peak soldering temperature                       |                                                                                                                      |     | -        | 260  | °C   |
| Source-drain         | diode                                            |                                                                                                                      |     | <u>'</u> | '    |      |
| I <sub>S</sub>       | source current                                   | T <sub>mb</sub> = 25 °C                                                                                              |     | -        | 200  | Α    |
| I <sub>SM</sub>      | peak source current                              | pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 °C$                                                                        |     | -        | 1159 | Α    |
| Avalanche ru         | ıggedness                                        |                                                                                                                      |     |          |      |      |
| E <sub>DS(AL)S</sub> | non-repetitive drain-<br>source avalanche energy | $I_D$ = 50 A; $V_{sup} \le 50$ V; $R_{GS}$ = 50 Ω; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; unclamped; $t_p$ = 513 μs | [2] | -        | 833  | mJ   |
|                      |                                                  | $I_D$ = 25 A; $V_{sup} \le 50$ V; $R_{GS}$ = 50 Ω; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; unclamped; $t_p$ = 2.5 ms | [2] | -        | 2    | J    |
| I <sub>AS</sub>      | non-repetitive avalanche current                 | $V_{sup} \le 50 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C};$<br>$R_{GS} = 50 \Omega$              | [2] | -        | 115  | А    |

<sup>[1] 200</sup>A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.



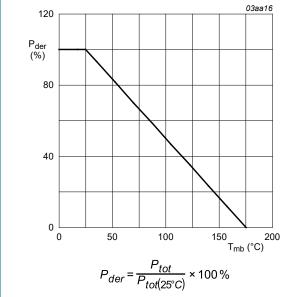
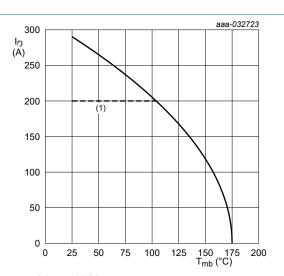
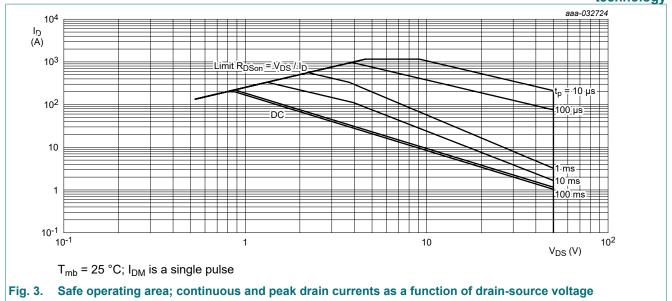


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



 $V_{GS} \ge 10 \text{ V}$  (1) 200A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

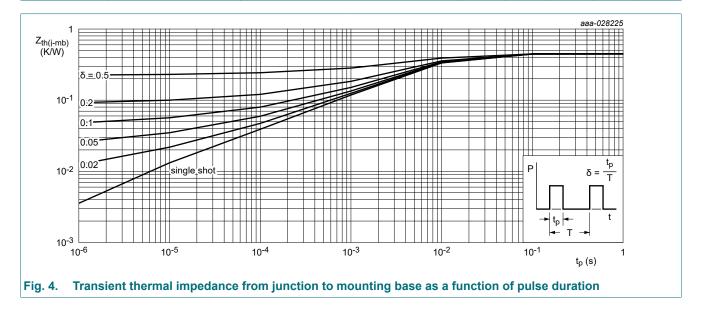
Fig. 2. Continuous drain current as a function of mounting base temperature

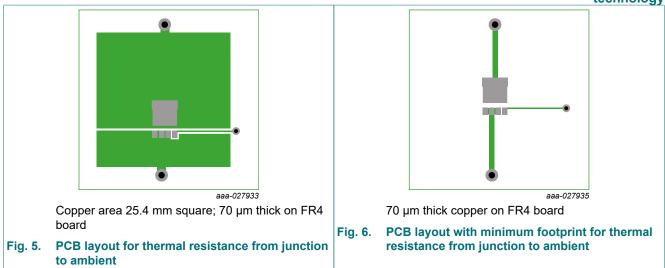


### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

| Symbol                | Parameter                                         | Conditions | Min | Тур  | Max  | Unit |
|-----------------------|---------------------------------------------------|------------|-----|------|------|------|
| R <sub>th(j-mb)</sub> | thermal resistance from junction to mounting base | Fig. 4     | -   | 0.33 | 0.45 | K/W  |
| R <sub>th(j-a)</sub>  | thermal resistance from                           | Fig. 5     | -   | 42   | -    | K/W  |
|                       | junction to ambient                               | Fig. 6     | -   | 85   | -    | K/W  |





### 10. Characteristics

**Table 7. Characteristics** 

| Symbol                       | Parameter                                                | Conditions                                                                                  | Min  | Тур  | Max  | Unit |
|------------------------------|----------------------------------------------------------|---------------------------------------------------------------------------------------------|------|------|------|------|
| Static charac                | teristics                                                |                                                                                             |      |      |      |      |
| V <sub>(BR)DSS</sub>         | drain-source                                             | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$                                                | 50   | -    | -    | V    |
|                              | breakdown voltage                                        | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$                                               | 45   | -    | -    | V    |
| $V_{GS(th)}$                 | gate-source threshold voltage                            | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$                                  | 1.2  | 1.61 | 2.2  | V    |
| $\Delta V_{GS(th)}/\Delta T$ | gate-source threshold voltage variation with temperature | 25 °C ≤ T <sub>j</sub> ≤ 150 °C                                                             | -    | -4.6 | -    | mV/K |
| I <sub>DSS</sub>             | drain leakage current                                    | V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C                       | -    | 0.01 | 1    | μΑ   |
|                              |                                                          | V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 125 °C                      | -    | 3.9  | -    | μΑ   |
| I <sub>GSS</sub>             | gate leakage current                                     | V <sub>GS</sub> = 16 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C                       | -    | 2    | 100  | nA   |
|                              |                                                          | V <sub>GS</sub> = -16 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C                      | -    | 2    | 100  | nA   |
| R <sub>DSon</sub>            | drain-source on-state resistance                         | $V_{GS}$ = 10 V; $I_D$ = 25 A; $T_j$ = 25 °C;<br>Fig. 10                                    | -    | 1.4  | 1.75 | mΩ   |
|                              |                                                          | V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 150 °C;<br>Fig. 11          | -    | -    | 3.52 | mΩ   |
|                              |                                                          | $V_{GS}$ = 4.5 V; $I_{D}$ = 25 A; $T_{j}$ = 25 °C;<br>Fig. 10                               | -    | 1.6  | 2    | mΩ   |
|                              |                                                          | $V_{GS}$ = 4.5 V; $I_{D}$ = 25 A; $T_{j}$ = 150 °C;<br>Fig. 11                              | -    | -    | 4.02 | mΩ   |
| R <sub>G</sub>               | gate resistance                                          | f = 1 MHz; T <sub>j</sub> = 25 °C                                                           | 0.52 | 1.3  | 3.3  | Ω    |
| Dynamic cha                  | racteristics                                             |                                                                                             | '    |      |      |      |
| Q <sub>G(tot)</sub>          | total gate charge                                        | I <sub>D</sub> = 25 A; V <sub>DS</sub> = 25 V; V <sub>GS</sub> = 4.5 V;<br>Fig. 12; Fig. 13 | -    | 53   | 82   | nC   |
|                              |                                                          | I <sub>D</sub> = 25 A; V <sub>DS</sub> = 25 V; V <sub>GS</sub> = 10 V;<br>Fig. 12; Fig. 13  | -    | 117  | 181  | nC   |
|                              |                                                          | I <sub>D</sub> = 0 A; V <sub>DS</sub> = 0 V; V <sub>GS</sub> = 10 V                         | -    | 61   | -    | nC   |

| Symbol                 | Parameter                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      | Conditions                                                                                 |     | Min | Тур  | Max   | Unit |
|------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------|-----|-----|------|-------|------|
| Q <sub>GS</sub>        | gate-source charge                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             | I <sub>D</sub> = 25 A; V <sub>DS</sub> = 25 V; V <sub>GS</sub> = 4.5 V;                    |     | -   | 17   | 26    | nC   |
| Q <sub>GS(th)</sub>    | pre-threshold gate-<br>source charge                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           | Fig. 12; Fig. 13                                                                           |     | -   | 11.3 | 17    | nC   |
| Q <sub>GS(th-pl)</sub> | post-threshold gate-<br>source charge                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          | _                                                                                          |     | -   | 5.4  | 8     | nC   |
| Q <sub>GD</sub>        | gate-drain charge                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |                                                                                            |     | -   | 13   | 29    | nC   |
| $V_{GS(pl)}$           | gate-source plateau voltage                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    | I <sub>D</sub> = 25 A; V <sub>DS</sub> = 25 V; <u>Fig. 12</u> ; <u>Fig. 13</u>             |     | -   | 2.5  | -     | V    |
| C <sub>iss</sub>       | input capacitance                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | V <sub>DS</sub> = 25 V; V <sub>GS</sub> = 0 V; f = 1 MHz;                                  |     | -   | 7959 | 11143 | pF   |
| C <sub>oss</sub>       | output capacitance                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             | T <sub>j</sub> = 25 °C; <u>Fig. 14</u>                                                     |     | -   | 799  | 1119  | pF   |
| C <sub>rss</sub>       | reverse transfer capacitance                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |                                                                                            |     | -   | 231  | 554   | pF   |
| t <sub>d(on)</sub>     | turn-on delay time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             | $V_{DS} = 25 \text{ V}; R_L = 1 \Omega; V_{GS} = 4.5 \text{ V};$                           |     | -   | 39   | -     | ns   |
| t <sub>r</sub>         | rise time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      | $R_{G(ext)} = 5 \Omega$                                                                    |     | -   | 40   | -     | ns   |
| t <sub>d(off)</sub>    | turn-off delay time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |                                                                                            |     | -   | 68   | -     | ns   |
| t <sub>f</sub>         | fall time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |                                                                                            |     | -   | 32   | -     | ns   |
| Q <sub>oss</sub>       | output charge                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  | $V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; f = 1 \text{ MHz};$<br>$T_j = 25 \text{ °C}$ |     | -   | 42   | -     | nC   |
| Source-drain           | n diode                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |                                                                                            |     |     |      |       |      |
| V <sub>SD</sub>        | source-drain voltage                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           | $I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 15$             |     | -   | 0.75 | 1     | V    |
| t <sub>rr</sub>        | reverse recovery time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          | $I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$          |     | -   | 36   | -     | ns   |
| Q <sub>r</sub>         | recovered charge                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | V <sub>DS</sub> = 25 V; <u>Fig. 16</u>                                                     | [1] | -   | 37   | -     | nC   |
| t <sub>a</sub>         | reverse recovery rise time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |                                                                                            |     | -   | 21   | -     | ns   |
| t <sub>b</sub>         | reverse recovery fall time                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |                                                                                            |     | -   | 14   | -     | ns   |
|                        | The state of the s | 1                                                                                          |     | 1   | 1    | 1     | 1    |

#### [1] includes capacitive recovery

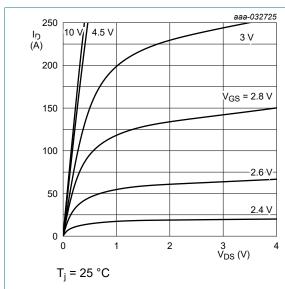


Fig. 7. Output characteristics; drain current as a function of drain-source voltage; typical values

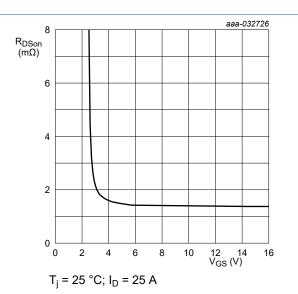


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

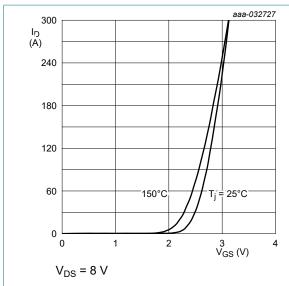


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

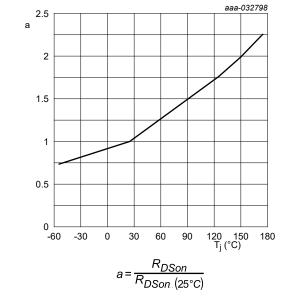


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

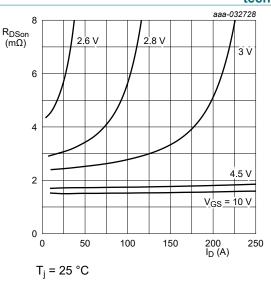


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

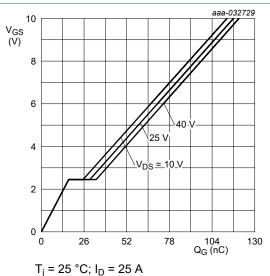


Fig. 12. Gate-source voltage as a function of gate charge; typical values

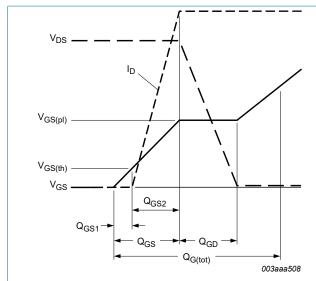
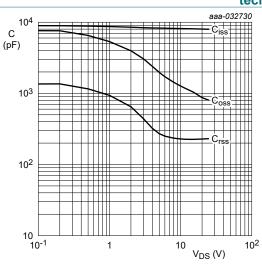


Fig. 13. Gate charge waveform definitions



 $V_{GS} = 0 V; f = 1 MHz$ 

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

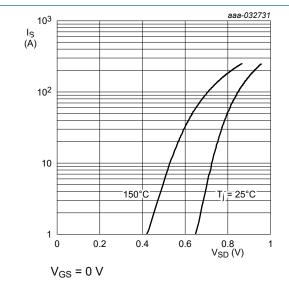


Fig. 15. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

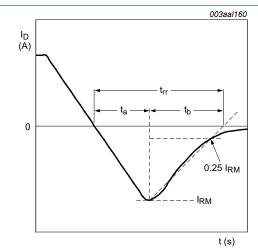


Fig. 16. Reverse recovery timing definition

# 11. Package outline

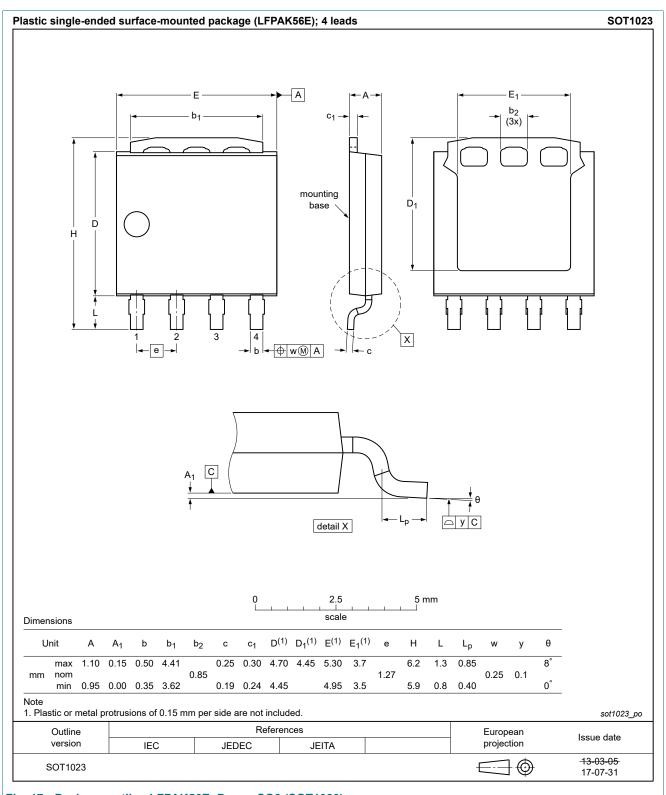
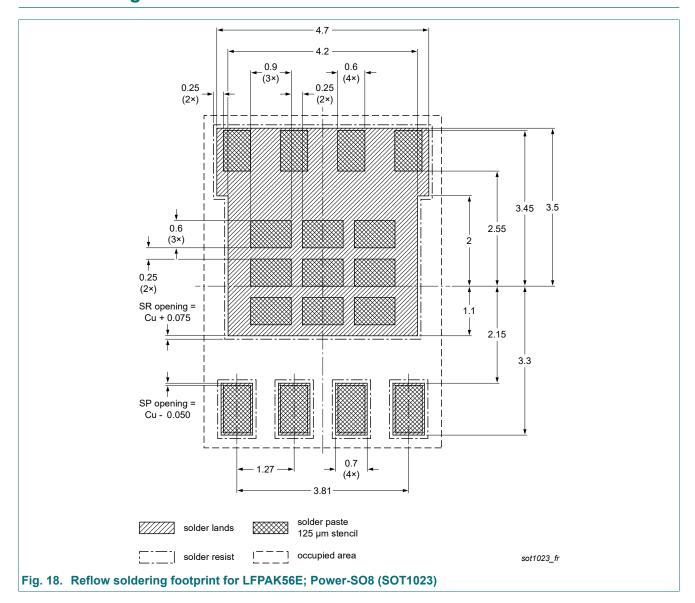


Fig. 17. Package outline LFPAK56E; Power-SO8 (SOT1023)

# 12. Soldering



## 13. Legal information

#### Data sheet status

| Document status [1][2]         | Product<br>status [3] | Definition                                                                            |
|--------------------------------|-----------------------|---------------------------------------------------------------------------------------|
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